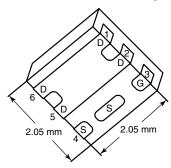
Vishay Siliconix

P-Channel 20 V (D-S) MOSFET

PRODUCT SUMMARY									
V _{DS} (V)	R _{DS(on)} (Ω) (Max.)	I _D (A) ^a	Q _g (Typ.)						
- 20	0.0350 at V _{GS} = - 4.5 V	- 9							
	0.0395 at V _{GS} = - 3.7 V	- 9	10 nC						
	0.0620 at V _{GS} = - 2.5 V	- 9							

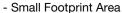
PowerPAK SC-70-6L-Single



Ordering Information: SiA459EDJ-T1-GE3 (Lead (Pb)-free and Halogen-free)

FEATURES

- TrenchFET® Power MOSFET
- Thermally Enhanced PowerPAK® SC-70 Package



- Low On-Resistance
- 100 % R_g Tested

• Typical ESD Protection: 2000 V (HBM)

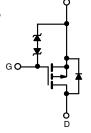
· Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

RoHS COMPLIANT HALOGEN

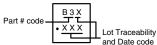
FREE

APPLICATIONS

- · Portable Devices such as Smart Phones, Tablet PCs and Mobile Computing
 - DC/DC Converter
 - Battery Switch
 - Load Switch
 - Power Management







P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)								
Parameter		Symbol	Limit	Unit				
Drain-Source Voltage		V_{DS}	- 20	V				
Gate-Source Voltage		V _{GS}	± 12	V				
	T _C = 25 °C		- 9ª					
Continuous Duois Courset /T 150 °C)	T _C = 70 °C	. [- 9 ^a					
Continuous Drain Current (T _J = 150 °C)	T _A = 25 °C	I _D	- 7.4 ^{b, c}					
	T _A = 70 °C	Γ	- 6 ^{b, c}	Α				
Pulsed Drain Current (t = 100 μs)		I _{DM}	- 40	I				
Castiana Camara Busia Biada Comunit	T _C = 25 °C		- 9 ^a					
Continuous Source-Drain Diode Current	T _A = 25 °C	l _S –	- 2.4 ^{b, c}					
	T _C = 25 °C		15.6					
Martin as Barras Biratas Barras	T _C = 70 °C		10	١,,,				
Maximum Power Dissipation	T _A = 25 °C	P _D	2.9 ^{b, c}	W				
	T _A = 70 °C		1.8 ^{b, c}					
Operating Junction and Storage Temperature Rar	nge	T _J , T _{stg}	- 50 to 150	°C				
Soldering Recommendations (Peak Temperature)	d, e		260					

THERMAL RESISTANCE RATINGS									
Parameter		Symbol	Typical	Maximum	Unit				
Maximum Junction-to-Ambient ^{b, f}	t ≤ 5 s	R _{thJA}	32	43	°C/W				
Maximum Junction-to-Case (Drain)	Steady State	R _{thJC}	6	8	C/VV				

Notes

a. Package limited.

S13-2182-Rev. A, 14-Oct-13

- b. Surface mounted on 1" x 1" FR4 board.
- c. t = 5 s.
- d. See solder profile (<u>www.vishay.com/doc?73257</u>). The PowerPAK SC-70 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.
- Maximum under steady state conditions is 80 °C/W.



www.vishay.com

Vishay Siliconix

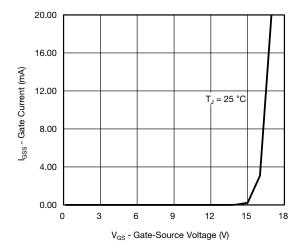
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit		
Static								
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$	- 20			V		
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$			- 12		mV/°C		
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	I _D = - 250 μA		2.2				
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = -250 \mu A$	- 0.6		- 1.2	V		
		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V}$			± 10			
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 4.5 \text{ V}$			± 0.5			
		V _{DS} = - 20 V, V _{GS} = 0 V			- 1	μΑ		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = - 20 V, V _{GS} = 0 V, T _J = 55 °C			- 10			
On-State Drain Currenta	I _{D(on)}	$V_{DS} \le -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	- 10			Α		
	(* /	V _{GS} = - 4.5 V, I _D = - 5 A		0.0280	0.0350	Ω		
Drain-Source On-State Resistancea	R _{DS(on)}	V _{GS} = - 3.7 V, I _D = - 5 A		0.0310	0.0395			
	- (,	V _{GS} = - 2.5 V, I _D = - 2 A		0.0450	0.0620			
Forward Transconductancea	9 _{fs}	V _{GS} = - 10 V, I _D = - 5 A		15		S		
Dynamic ^b								
Input Capacitance	C _{iss}			885		pF		
Output Capacitance	C _{oss}	$V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		155				
Reverse Transfer Capacitance	C _{rss}			140				
Tabal Oaks Observe		$V_{DS} = -10 \text{ V}, V_{GS} = -10 \text{ V}, I_D = -5 \text{ A}$		20	30	nC		
Total Gate Charge	Q_g			10	15			
Gate-Source Charge	Q_{gs}	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -5 \text{ A}$		1.6				
Gate-Drain Charge	Q_{gd}			2.9				
Gate Resistance	R _q	f = 1 MHz	2.2	11	22	Ω		
Turn-On Delay Time	t _{d(on)}			20	40			
Rise Time	t _r	$V_{DD} = -10 \text{ V}, R_L = 1.67 \Omega$		25	50			
Turn-Off Delay Time	t _{d(off)}	$I_D \cong$ - 6 A, V_{GEN} = - 4.5 V, R_g = 1 Ω		40	80			
Fall Time	t _f			20	40			
Turn-On Delay Time	t _{d(on)}			7	15	ns		
Rise Time	t _r	$V_{DD} = -10 \text{ V}, R_L = 1.67 \Omega$		10	20			
Turn-Off Delay Time	t _{d(off)}	$I_D \cong$ - 6 A, V_{GEN} = - 10 V, R_g = 1 Ω		40	80			
Fall Time	t _f			20	40			
Drain-Source Body Diode Characterist	ics							
Continuous Source-Drain Diode Current	Is	T _C = 25 °C			- 9	^		
Pulse Diode Forward Current	I _{SM}				- 40	Α		
Body Diode Voltage	V_{SD}	I _S = -6 A, V _{GS} = 0 V		- 0.9	- 1.2	V		
Body Diode Reverse Recovery Time	t _{rr}			21	35	ns		
Body Diode Reverse Recovery Charge	Q _{rr}	$I_F = -6 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s},$		9	20	nC		
Reverse Recovery Fall Time	t _a	$T_J = 25 ^{\circ}C$		7				
· · · · · · · · · · · · · · · · · · ·						ns		

Notes

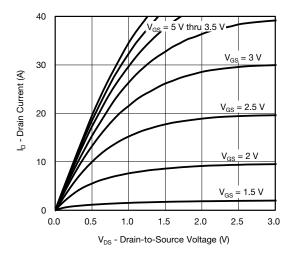
- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

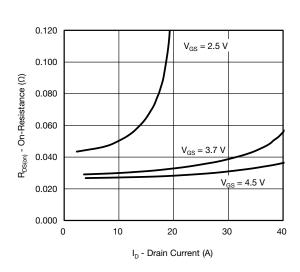




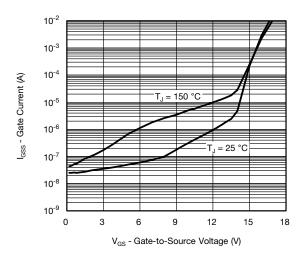
Gate Current vs. Gate-Source Voltage



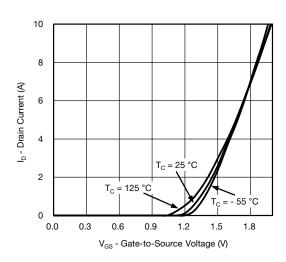
Output Characteristics



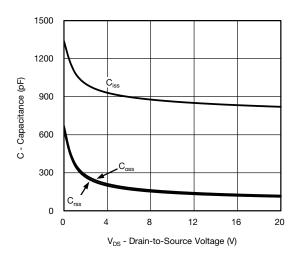
On-Resistance vs. Drain Current and Gate Voltage



Gate Current vs. Gate-to-Source Voltage

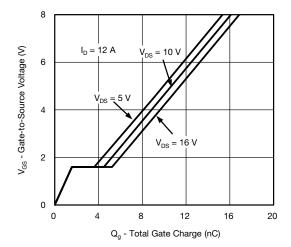


Transfer Characteristics

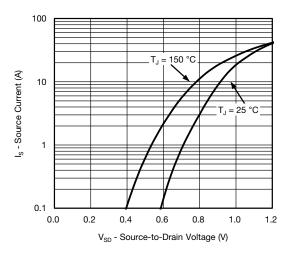


Capacitance

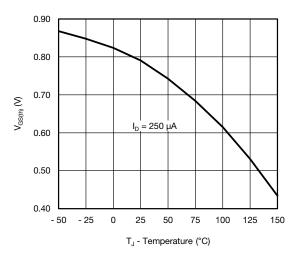




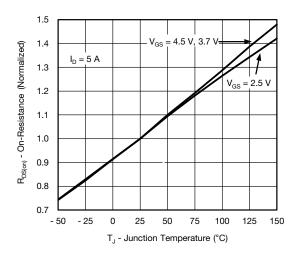
Gate Charge



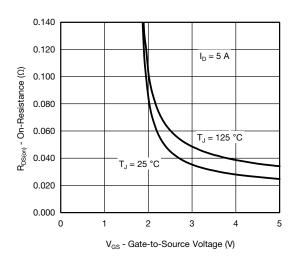
Soure-Drain Diode Forward Voltage



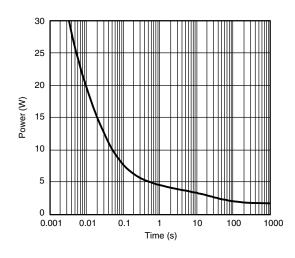
Threshold Voltage



On-Resistance vs. Junction Temperature

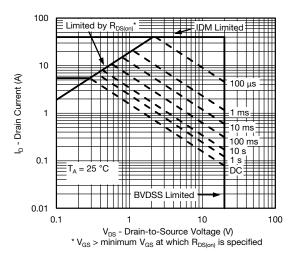


On-Resistance vs. Gate-to-Source Voltage

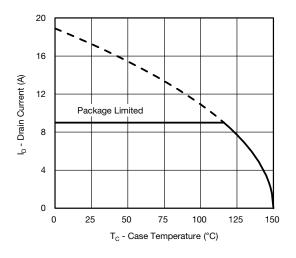


Single Pulse Power, Junction-to-Ambient

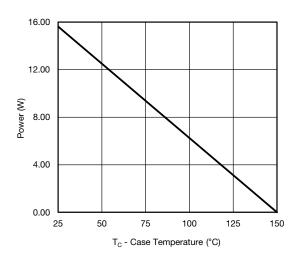




Safe Operating Area, Junction-to-Ambient



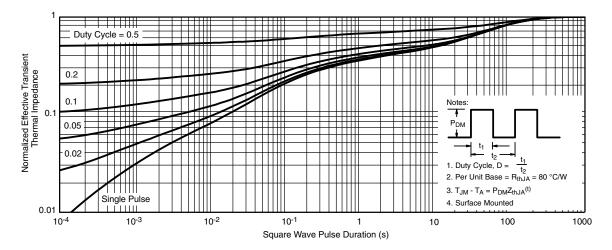




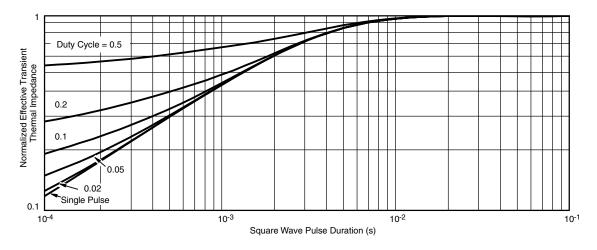
Power Derating

^{*} The power dissipation P_D is based on $T_{J(max.)} = 150$ °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.





Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?62912.

Vishay Siliconix

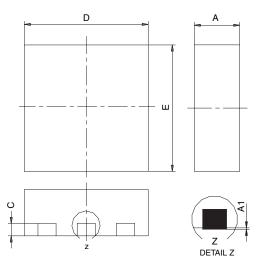
PowerPAK® SC70-6L





BACKSIDE VIEW OF SINGLE

BACKSIDE VIEW OF DUAL



- All dimensions are in millimeters
 Package outline exclusive of mold flash and metal burr
 Package outline inclusive of plating

		SINGLE PAD						DUAL PAD				
DIM	M	ILLIMETER	RS	INCHES			MILLIMETERS			INCHES		
	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max
Α	0.675	0.75	0.80	0.027	0.030	0.032	0.675	0.75	0.80	0.027	0.030	0.032
A1	0	-	0.05	0	-	0.002	0	-	0.05	0	-	0.002
b	0.23	0.30	0.38	0.009	0.012	0.015	0.23	0.30	0.38	0.009	0.012	0.015
С	0.15	0.20	0.25	0.006	0.008	0.010	0.15	0.20	0.25	0.006	0.008	0.010
D	1.98	2.05	2.15	0.078	0.081	0.085	1.98	2.05	2.15	0.078	0.081	0.085
D1	0.85	0.95	1.05	0.033	0.037	0.041	0.513	0.613	0.713	0.020	0.024	0.028
D2	0.135	0.235	0.335	0.005	0.009	0.013						
E	1.98	2.05	2.15	0.078	0.081	0.085	1.98	2.05	2.15	0.078	0.081	0.085
E1	1.40	1.50	1.60	0.055	0.059	0.063	0.85	0.95	1.05	0.033	0.037	0.041
E2	0.345	0.395	0.445	0.014	0.016	0.018						
E3	0.425	0.475	0.525	0.017	0.019	0.021						
е		0.65 BSC		0.026 BSC			0.65 BSC			0.026 BSC		
K		0.275 TYP	1		0.011 TYP	1	0.275 TYP			0.011 TYP		
K1		0.400 TYP	TYP 0.016 TYP			0.320 TYP			0.013 TYP			
K2		0.240 TYP 0.009 TYP			0.252 TYP			0.010 TYP				
К3		0.225 TYP	1	0.009 TYP								
K4		0.355 TYP	<u> </u>	0.014 TYP								
L	0.175	0.275	0.375	0.007	0.011	0.015	0.175	0.275	0.375	0.007	0.011	0.015
Т							0.05	0.10	0.15	0.002	0.004	0.006
FCN: C-07431 – Rev. C. 06-Aug-07												

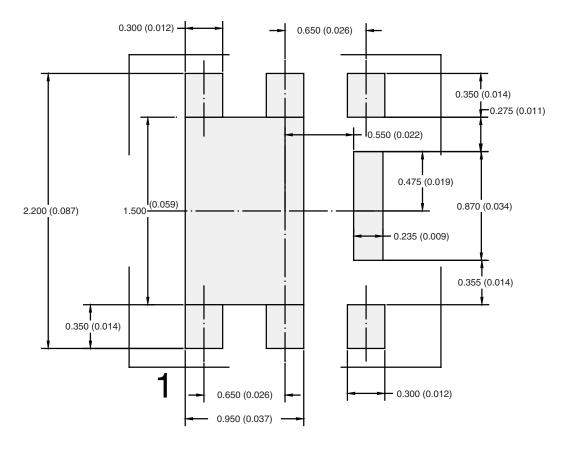
DWG: 5934

Document Number: 73001 06-Aug-07

www.vishay.com



RECOMMENDED PAD LAYOUT FOR PowerPAK® SC70-6L Single



Dimensions in mm/(Inches)

Return to Index

ATTLICATION NOT



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

单击下面可查看定价,库存,交付和生命周期等信息

>>Vishay(威世)